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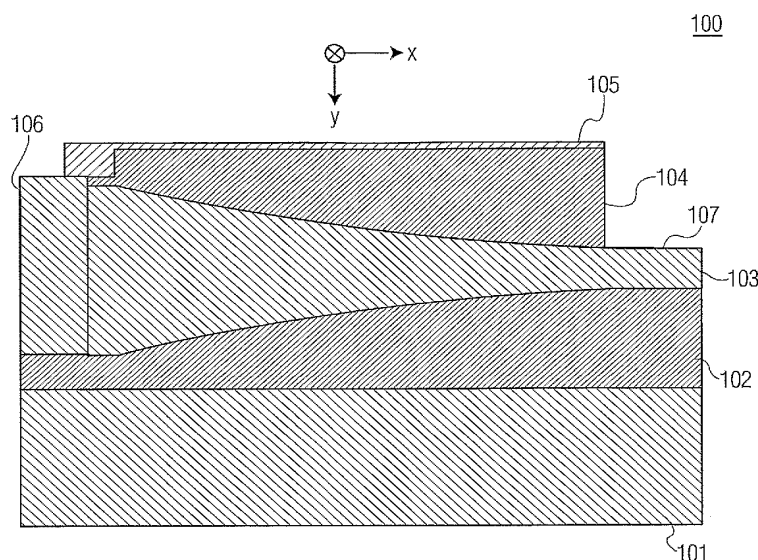
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(54) Title: TAPERED UNIT CELL METAL-OXIDE-SEMICONDUCTOR HIGH-VOLTAGE DEVICE STRUCTURE



(57) Abstract: A field effect electronic device (e.g., an FET) includes a field plate disposed over a dielectric layer, which is disposed over a semiconductor layer, wherein a drift region of the device is in the semiconductor layer. A doping level varies substantially non-linearly across the drift region, and the device exhibits a substantially constant reduced surface electric field. A method of fabricating a field effect device includes providing a non-linear non-uniform doping density in a drift region of a semiconductor layer of the device wherein both the semiconductor layer and the dielectric layer have non-constant thickness.

**Declarations under Rule 4.17:**

- as to applicant's entitlement to apply for and be granted a patent (Rule 4.17(ii)) for the following designations AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SM, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, UZ, VC, VN, YU, ZA, ZM, ZW, ARIPO patent (BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW), Eurasian patent (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European patent (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR,

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